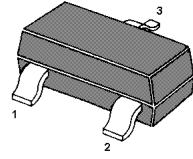


MMBTSC2223

NPN Silicon Epitaxial Planar Transistor

High frequency amplifier

The transistor is subdivided into three groups, R, O and Y, according to its DC current gain.



1.BASE 2.EMITTER 3.COLLECTOR
SOT-23 Plastic Package

Absolute Maximum Ratings ($T_a = 25\text{ }^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Collector Base Voltage	V_{CBO}	30	V
Collector Emitter Voltage	V_{CEO}	20	V
Emitter-Base Voltage	V_{EBO}	4	V
Collector Current	I_C	20	mA
Power Dissipation	P_{tot}	200	mW
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	- 55 + 150	$^\circ\text{C}$

Characteristics at $T_{amb}=25\text{ }^\circ\text{C}$

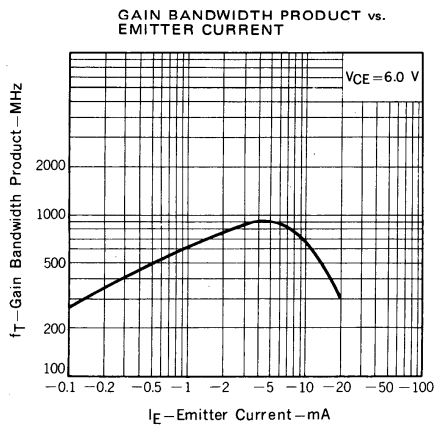
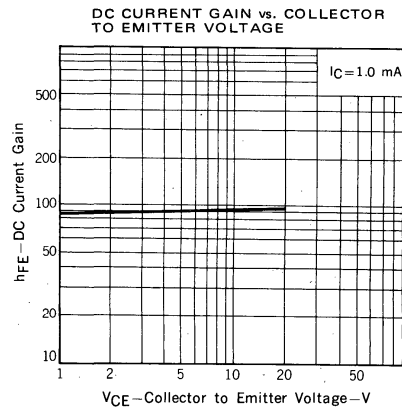
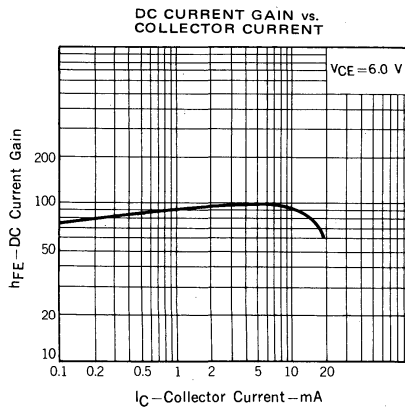
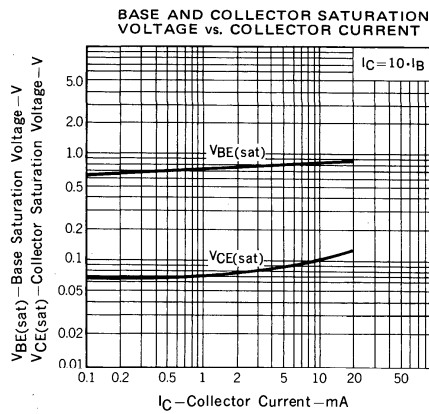
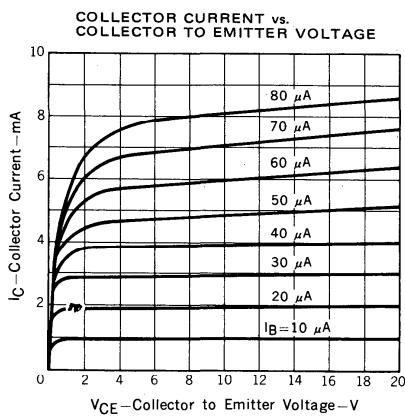
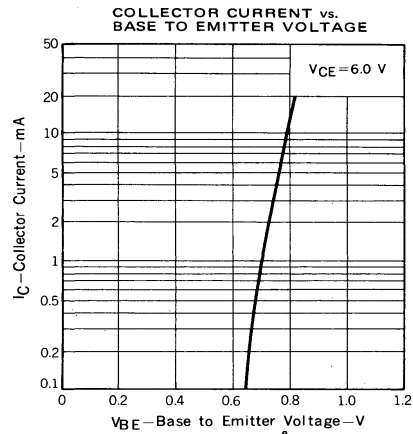
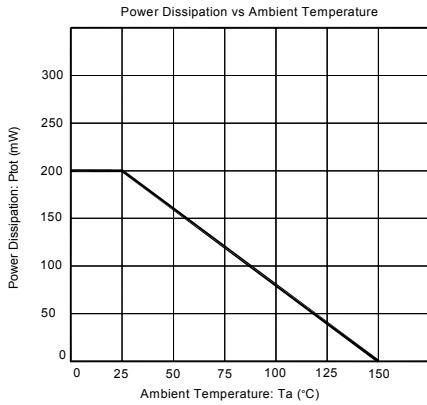
Parameter	Symbol	Min.	Typ.	Max.	Unit
DC Current Gain at $V_{CE} = 6\text{ V}$, $I_C = 1\text{ mA}$ Current Gain Group	R h_{FE}	40	-	80	-
	O h_{FE}	60	-	120	-
	Y h_{FE}	90	-	180	-
Collector Base Cutoff Current at $V_{CB} = 30\text{ V}$	I_{CBO}	-	-	100	nA
Emitter Base Cutoff Current at $V_{EB} = 4\text{ V}$	I_{EBO}	-	-	100	nA
Collector Base Breakdown Voltage at $I_C = 10\text{ }\mu\text{A}$	$V_{(BR)CBO}$	30	-	-	V
Collector Emitter Breakdown Voltage at $I_C = 1\text{ mA}$	$V_{(BR)CEO}$	20	-	-	V
Emitter Base Breakdown Voltage at $I_E = 10\text{ }\mu\text{A}$	$V_{(BR)EBO}$	4	-	-	V
Collector Emitter Saturation Voltage at $I_C = 10\text{ mA}$, $I_B = 1\text{ mA}$	$V_{CE(sat)}$	-	-	0.3	V
Gain Bandwidth Product at $V_{CE} = 6\text{ V}$, $-I_E = 1\text{ mA}$	f_T	-	600	-	MHz
Output Capacitance at $V_{CB} = 6\text{ V}$, $I_E = 0$, $f = 1\text{ MHz}$	C_{ob}	-	1	-	pF

TOP DYNAMIC



ISO14001 : 2004 ISO 9001 : 2008 OHSAS 18001 : 2007 IECQ QC 080000
Certificate No. 121505007 Certificate No. 01114012 Certificate No. 05131509008 Certificate No. 0501000714002
Dated: 11/08/2012 Rev: 01

MMBTSC2223



TOP DYNAMIC



ISO14001:2004 Certificate No. 121505007
 ISO 9001:2008 Certificate No. 50114012
 OHSAS 18001:2007 Certificate No. 05131509008
 IECQ QC 080000 Certificate No. EC01000714002

Dated: 11/08/2012 Rev: 01